onsemi

NPN Epitaxial Silicon Transistor

KSP10

Features

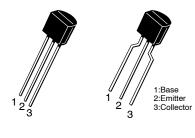
- VHF/UHF Transistor
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

ABSOLUTE MAXIMUM RATINGS

Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Value	Unit	
V _{CBO}	Collector-Base Voltage	30	V	
V _{CEO}	Collector-Emitter Voltage	25	V	
V _{EBO}	Emitter-Base Voltage	3.0	V	
PC	Collector Power Dissipation (T _A = 25° C)	350	mW	
	Derate above 25°C	2.8	mW/°C	
PC	Collector Power Dissipation (T _C = 25° C)	1.0	W	
	Derate above 25°C	8.0	W/°C	
TJ	Junction Temperature	150	°C	
T _{STG}	Storage Temperature	–55 to 150	°C	
Rth(j-c)	Thermal Resistance, Junction to Case	125	°C/W	
Rth(j-a)	Rth(j-a) Thermal Resistance, Junction to Ambient		°C/W	

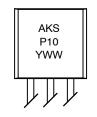
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



TO-92-3 CASE 135AN

TO-92 LF CASE 135AR

MARKING DIAGRAM



A = Assembly Code KSP10 = Device Code Y = Year WW = Work Week

ORDERING INFORMATION

Device	Package	Shipping
KSP10BU	TO–92 3 (Pb–Free)	10000 / Bulk Bag
KSP10TA	TO–92 3 LF (Pb–Free)	2000 / Fan-Fold

KSP10

Symbol	Parameter	Conditions	Min	Max	Unit
BV _{CBO}	Collector-Base Breakdown Voltage	I _C = 100 μA, I _E = 0	30	-	V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C = 1 mA, I _B = 0	25	-	V
BV_{EBO}	Emitter-Base Breakdown Voltage	$I_{E} = 10 \ \mu A, \ I_{C} = 0$	3.0	-	V
I _{CBO}	Collector Cut-Off Current	$V_{CB} = 25 \text{ V}, \text{ I}_{E} = 0$	-	100	nA
I _{EBO}	Emitter Cut-Off Current	$V_{EB} = 2 V, I_C = 0$	-	100	nA
h _{FE}	DC Current Gain	V _{CE} = 10 V, I _C = 4 mA	60	-	-
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = 4 mA, I _B = 0.4 mA	-	0.5	V
V _{BE(on)}	Base-Emitter On Voltage	V _{CE} = 10 V, I _C = 4 mA	-	0.95	V
f _T	Current Gain Bandwidth Product	V _{CE} = 10 V, I _C = 4 mA, f = 100 MHz	650	-	MHz
C _{ob}	Output Capacitance	$V_{CB} = 10 \text{ V}, \text{ I}_{E} = 0, \text{ f} = 1 \text{ MHz}$	-	0.7	pF
Crb	Collector Base Feedback Capacitance	V _{CB} = 10 V, I _E = 0, f = 1 MHz	0.35	0.65	pF
$C_{c\cdot rbb'}$	Collector Base Time Constant	V_{CB} = 10 V, I _C = 4 mA, f = 31.8 MHz	-	9.0	ps

ELECTRICAL CHARACTERISTICS (Values are at $T_A = 25^{\circ}C$ unless otherwise noted.)

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 1. Pulse Test: $PW \le 300 \ \mu$ s, Duty Cycle $\le 2\%$.

KSP10

TYPICAL CHARACTERISTICS

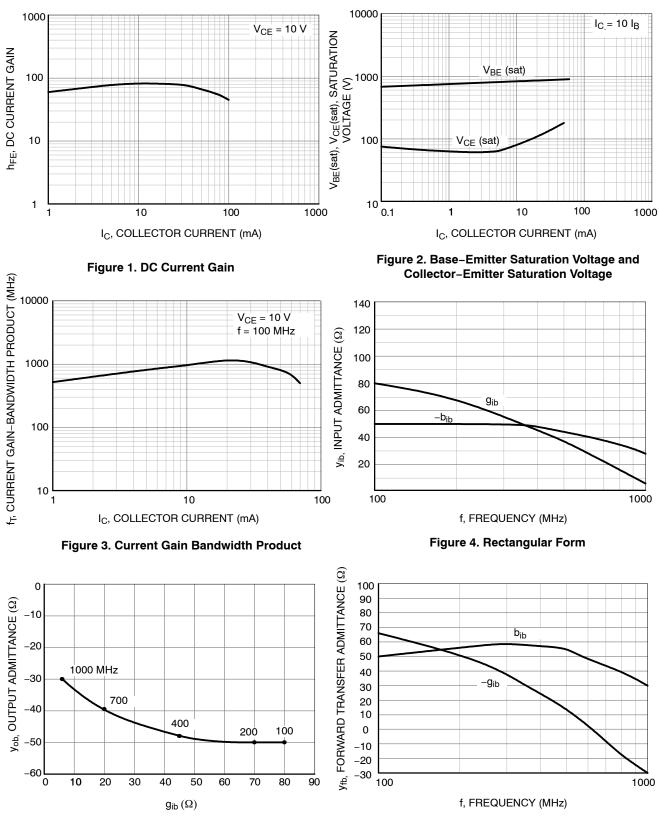
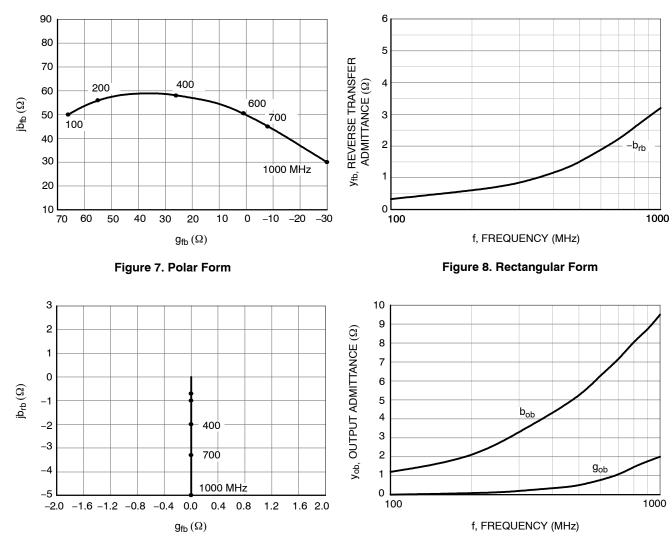


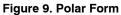
Figure 5. Polar Form

Figure 6. Rectangular Form

KSP10

TYPICAL CHARACTERISTICS (CONTINUED)





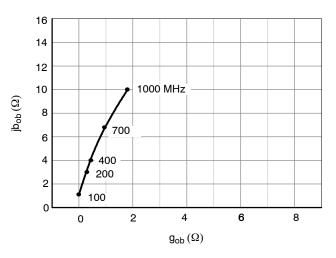


Figure 11. Polar Form

Figure 10. Rectangular Form

onsemi

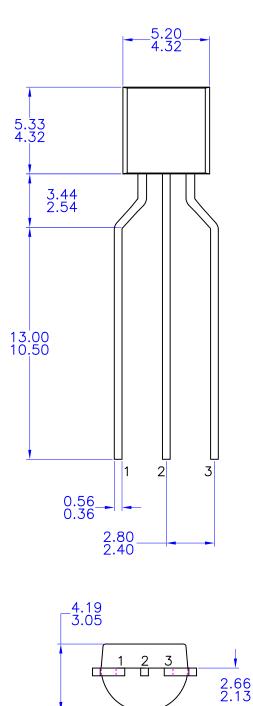
TO-92 3 4.825x4.76 CASE 135AN ISSUE O DATE 31 JUL 2016 _5.20_ ______ 5.33 (0.81) 15.62 2 3 1 0.52 0.56 0.36 1.27 NOTES: UNLESS OTHERWISE SPECIFIED 2.54 A) DRAWING WITH REFERENCE TO JEDEC TO-92 RECOMMENDATIONS. B) ALL DIMENSIONS ARE IN MILLIMETERS. с́э DRAWING CONFORMS TO ASME Y14.5M-2009. 4.19 3.05 2.66 2.13 2 3 1 Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. **DOCUMENT NUMBER:** 98AON13880G **DESCRIPTION:** TO-92 3 4.825X4.76 PAGE 1 OF 1

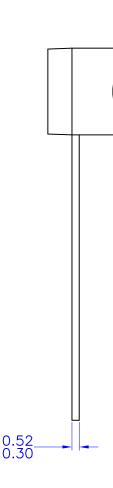
onsemi and ONSEMI are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.



TO-92 3 4.83x4.76 LEADFORMED CASE 135AR ISSUE O

DATE 30 SEP 2016





NOTES: UNLESS OTHERWISE SPECIFIED

A) DRAWING WITH REFERENCE TO JEDEC TO-92 RECOMMENDATIONS.

- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DRAWING CONFORMS TO ASME Y14.5M-1994

DOCUMENT NUMBER:	R: 98AON13879G Electronic versions are uncontrolled except when accessed directly from the Docum Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in r		
DESCRIPTION:	TO-92 3 4.83X4.76 LEADFORMED		PAGE 1 OF 1

onsemi and ONSEMi are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent_Marking.pdf</u>. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or indental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification. Buyer shall indemnify and hold onsemi and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs,

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

Technical Library: www.onsemi.com/design/resources/technical-documentation onsemi Website: www.onsemi.com

ONLINE SUPPORT: <u>www.onsemi.com/support</u> For additional information, please contact your local Sales Representative at <u>www.onsemi.com/support/sales</u>